



HW

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appl. No. : 10/727,595
Applicant : Gerhard Enders
Filed : December 5, 2003
TC/A.U. : 2811
Examiner : OWENS, Douglas W.
Confirmation No. : 7500
Docket No. : 0928.0006C
Customer No. : 27896
Title : Integrated Semiconductor Memory with a Selection
Transistor Formed at a Ridge (as amended)

Commissioner for Patents
P.O. Box 1450
Alexandria, Virginia 22313-1450

TRANSMITTAL LETTER

Enclosed are the following documents in response to the Notice of Non-Compliant Amendment mailed March 21, 2005 for the above-identified application:

- ☒ Response (2 Pages)
- ☒ Copy of Amendment dated February 25, 2005,
as originally filed (19 pages).
- ☐ Petition for Extension of Time
- ☐ Request for Approval of Drawing Changes
- ☐ Notice of Appeal
- ☐ Associate Power
- ☐ Revocation and New Power
- ☐ Change of Address
- ☐ Return receipt postcard
- ☐ Check No. _____ in the amount of \$ _____ for the total fee as calculated below
- ☐ Other:



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AMENDMENT

Sir:

In response to the Office Action mailed December 1, 2004, please amend the above-identified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims, which begins on page 13 of this paper.

Amendments to the Abstract begin on page 17 of this paper.

Remarks begin on page 18 of this paper.